

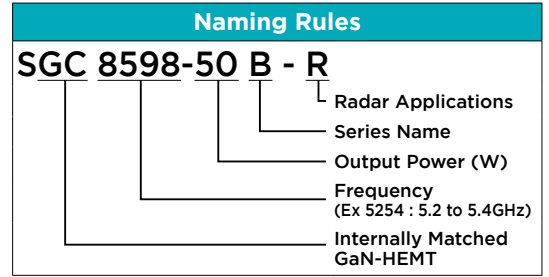
# Wireless Device Products 2026



# GaN HEMTs for Radar C/X-band

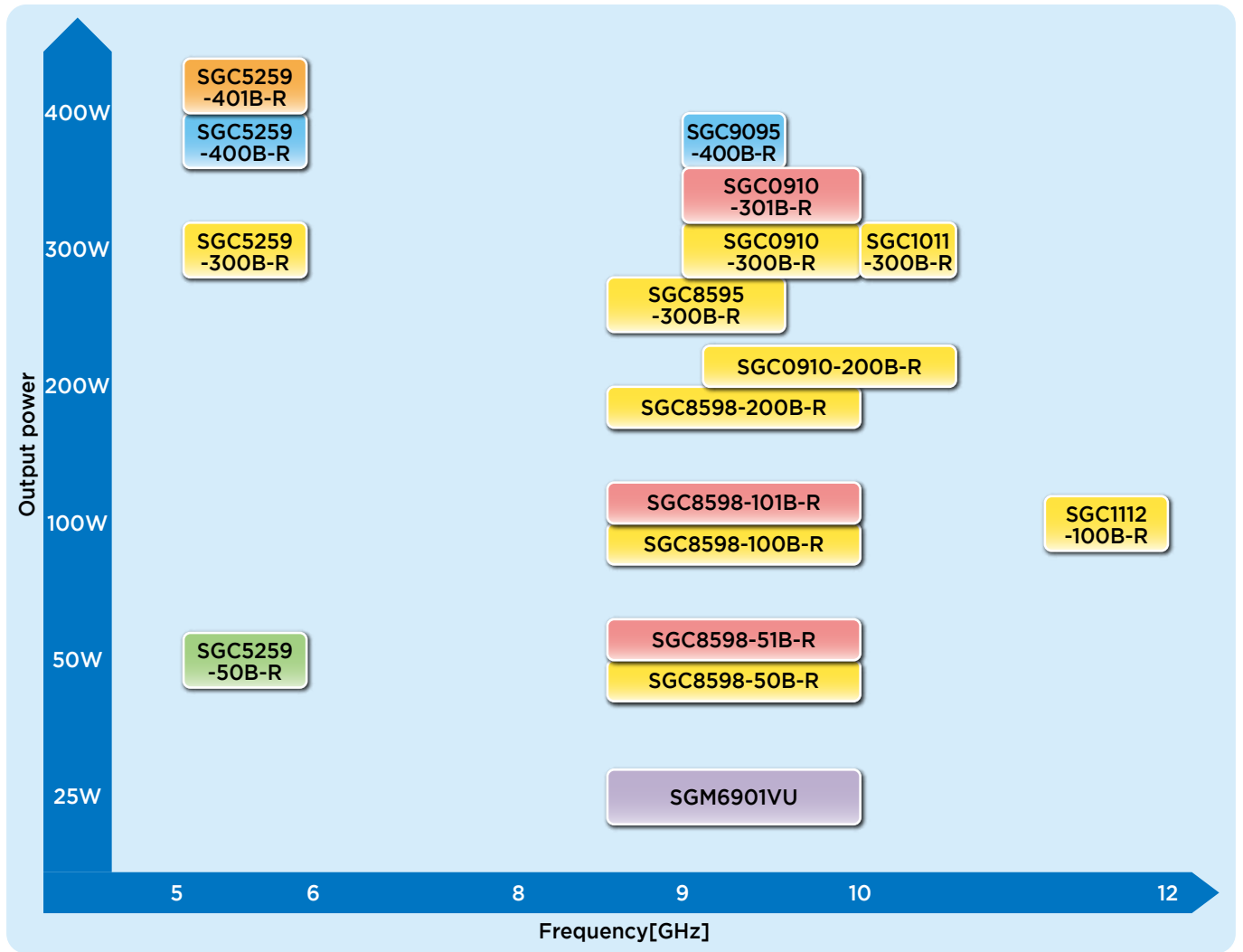
## Features

- High Power up to 520W(Typ.)
- High Gain
- High Efficiency
- Broad Band
- Impedance Matched  $Z_{in}/Z_{out} = 50\Omega$
- Small Flangeless Package



## GaN HEMTs for Radar C/X Lineup

- I2K Package   
 ■ IBK Package   
 ■ IK Package   
 ■ I2F Package   
 ■ I2G Package   
 ■ VU Package



## Product Photo





Part Number	Freq. (GHz)	Pout Typ. (dBm)	Gp Typ. (dB)	Efficiency (%)	VDS (V)	IDS(DC) (A)	Conditions Pulse Width/Duty	Pkg	
SGC5259-50B-R	5.2-5.9	48	13	51	50	0.17	100μs/10%	IBK	
SGC5259-300B-R	5.2-5.9	55.8(~5.7) 55.4(5.7~)	13.8(~5.7) 13.4(5.7~)	51	50	1		IK	
SGC5259-400B-R	5.2-5.9	57.2	14.2	50	50	1.3		I2F	
SGC5259-401B-R	5.2-5.9	57.2	14.2	50	50	1.3		I2G	
SGC8598-50B-R	8.5-9.8	48	11	41	50	0.17		IK	
SGC8598-51B-R	8.5-9.8	48	11	41	50	0.17		I2K	
SGC8598-100B-R	8.5-9.8	51	10	41	50	0.33		IK	
SGC8598-101B-R	8.5-9.8	51	10	39	50	0.33		I2K	
SGC8598-200B-R	8.5-9.8	54	10	39	50	0.66		IK	
SGC8595-300B-R	8.5-9.5	55.3(~9.17) 54.7(9.17~)	9.3(~9.17) 8.7(9.17~)	38	50	1			
SGC0910-200B-R	9.2-10.5	53.5(~10.1) 52.5(10.1~)	9.5(~10.1) 8.5(10.1~)	39	50	0.66			
SGC0910-300B-R	9-10	55.3(~9.6) 54.7(9.6~)	9.3(~9.6) 8.7(9.6~)	38	50	1			
SGC0910-301B-R	9-10	55.3(~9.6) 54.7(9.6~)	9.3(~9.6) 8.7(9.6~)	38	50	1			I2K
SGC9095-400B-R	9.0-9.5	56.5	8.5	38	50	1			I2F
SGC1011-300B-R	9.8-10.5	55(~10.3) 54.4(10.3~)	9.0(~10.3) 8.4(10.3~)	37	50	1			IK
SGC1112-100B-R	11.4-12	51	9	37	50	1			
SGM6901VU	8.5-10.1	45.3(~9.8) 44.8(9.8~)	23.3(~9.8) 22.8(9.8~)	38	50	0.2		VU	

I2G Package



# GaN HEMTs for Marine Radar

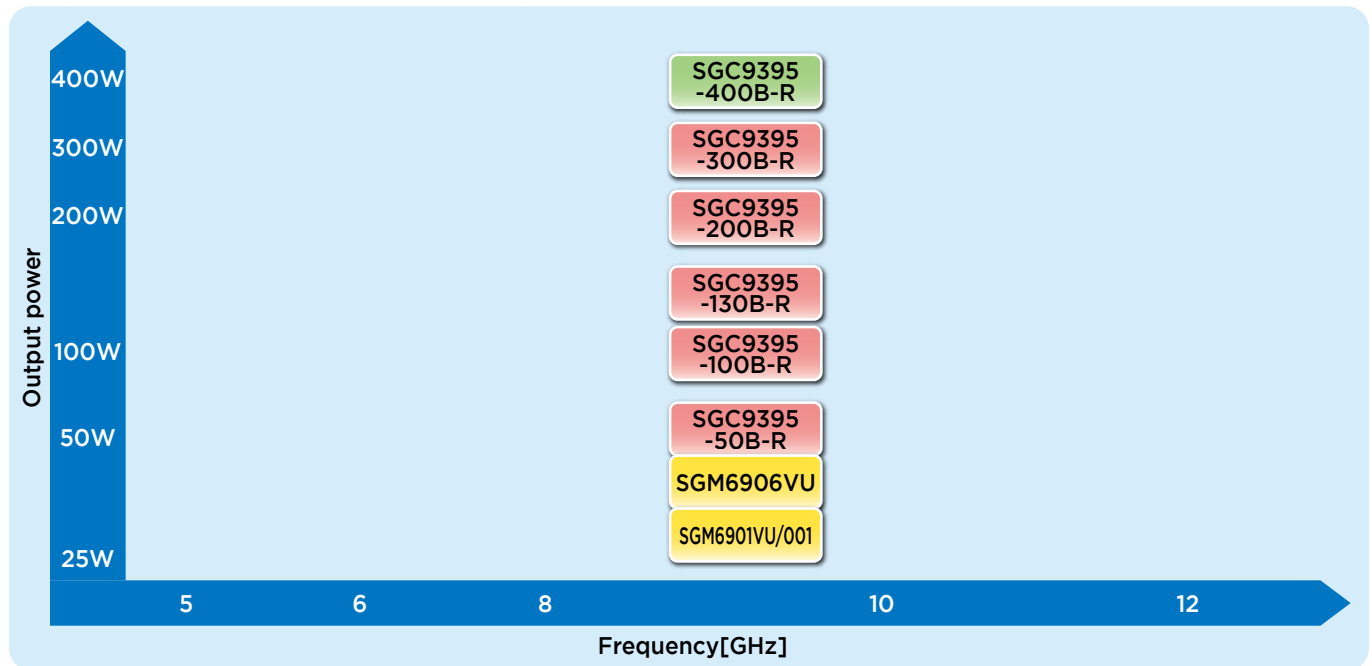
## Features

- High Power up to 450W(Typ.)
- High Gain
- High Efficiency
- For Marine Radar
- Impedance Matched  $Z_{in}/Z_{out} = 50\Omega$



## GaN HEMTs for Marine Radar Lineup

■ IK Package    
 ■ I2F Package    
 ■ VU Package



Part Number	Freq. (GHz)	Pout Typ. (dBm)	Gp Typ. (dB)	Efficiency (%)	VDS (V)	IDS(DC) (A)	Conditions Pulse Width/Duty	Pkg
SGC9395-50B-R	9.3-9.5	48	11	41	50	0.17	100µs/10%	IK
SGC9395-100B-R	9.3-9.5	51	10	41	50	0.33		
SGC9395-130B-R	9.3-9.5	52	10	39	50	0.5		
SGC9395-200B-R	9.3-9.5	54	10	39	50	0.66		
SGC9395-300B-R	9.3-9.5	55.3	9.3	38	50	1		
SGC9395-400B-R	9.3-9.5	56.5	8.5	38	50	1.3		I2F
SGM6906VU	9.2-9.5	47.5	22.5	37	50	0.2	50µs/5%	VU
SGM6901VU/001	9.3-9.5	45.3	23.3	38	50	0.2	100µs/10%	

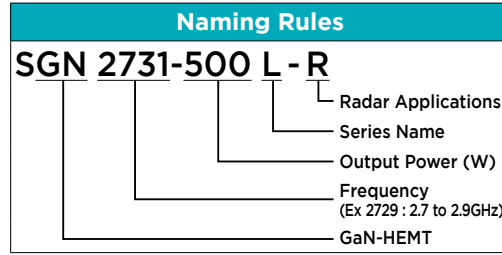
## Product Photo



# GaN HEMTs for Radar L/S-band

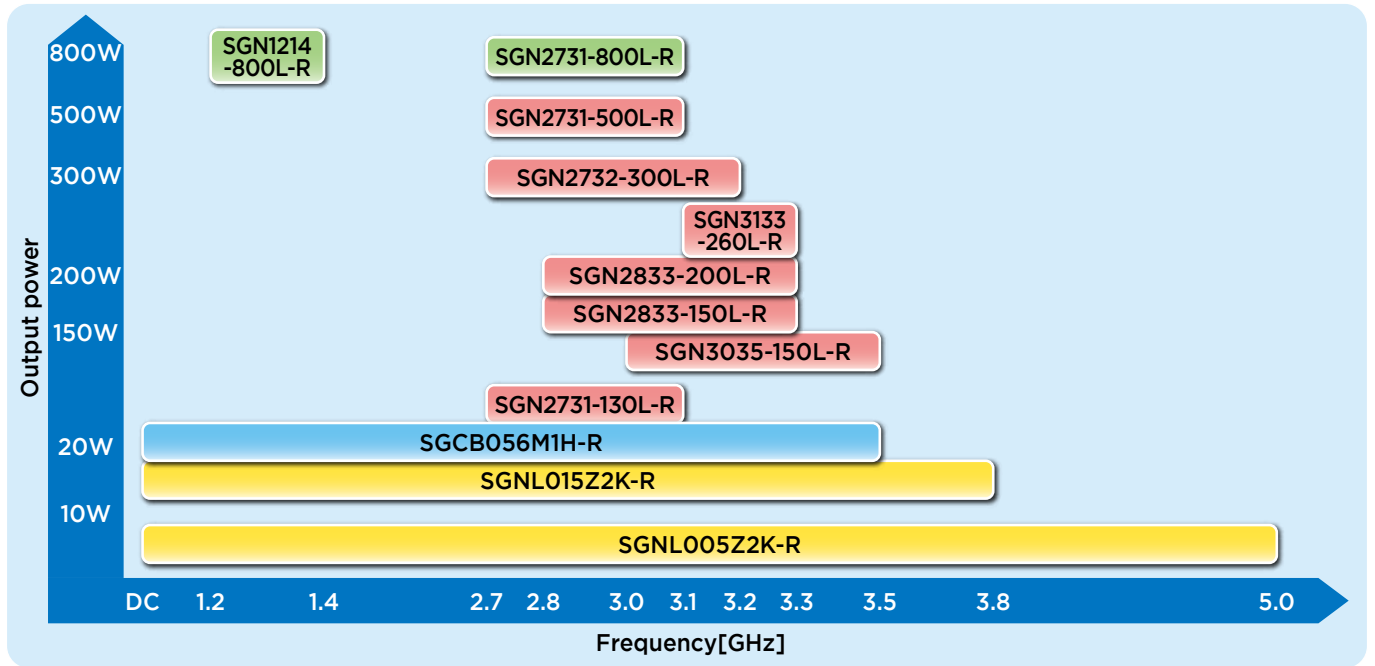
## Features

- High Power up to 1000W(Typ.)
- High Gain
- High Efficiency
- Broad Band



## GaN HEMTs for Radar L/S Lineup

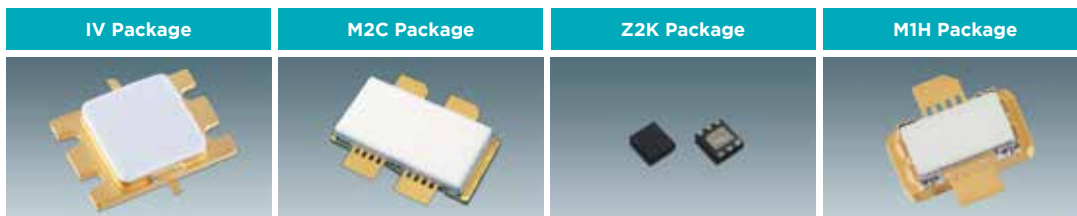
- IV Package
- M2C Package
- Z2K Package
- M1H Package



	Part Number	Freq. (GHz)	Pout Typ. (dBm)	Gp Typ. (dB)	Efficiency (%)	VDS (V)	IDS (DC)	Conditions Pulse Width/Duty	Pkg
*	SGNL005Z2K-R	DC-5.0	38.3 38.0	12.8 12.5	52 49	50	0.02	5µs/10% 3000µs/30%	Z2K
*	SGNL015Z2K-R	DC-3.8	42.4 42.1	11.9 11.6	56 53	50	0.06	5µs/10% 3000µs/30%	
*	SGCB056M1H-R	DC-3.5	47.5 47.2	13.5 13.2	60 57	50	0.13	200µs/10% 3000µs/30%	M1H
	SGN1214-800L-R	1.2-1.4	59	15	64	50	0.5	200µs/10%	M2C
*	SGN2731-130L-R	2.7-3.1	52.2 51.9	14.2 13.9	62 59	50	0.5	400µs/25% 3000µs/30%	IV
*	SGN3035-150L-R	3.0-3.5	52.8 52.3	13.8 13.5	62 59	50	0.5	200µs/10% 3000µs/30%	
*	SGN2833-150L-R	2.8-3.3	52.8 52.5	13.8 13.5	62 59	50	0.5	200µs/10% 3000µs/30%	
*	SGN2833-200L-R	2.8-3.3	54.0 53.7	12.0 11.7	60 57	50	0.5	200µs/10% 3000µs/30%	
	SGN3133-260L-R	3.1-3.3	55.1	11.4	57	32	1	200µs/10%	
	SGN2732-300L-R	2.7-3.2	55.5	15.5	62	50	1	200µs/10%	
	SGN2731-500L-R	2.7-3.1	57.4	12.4	57	50	1.5	120µs/10%	
	SGN2731-800L-R	2.7-3.1	60	15	60	50	0.5	200µs/10%	

\* Long pulse, High duty capable

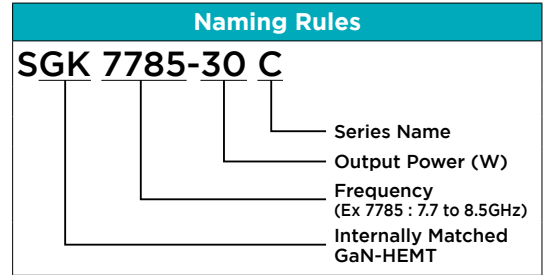
## Product Photo



# GaN HEMTs for Radio Link and SATCOM

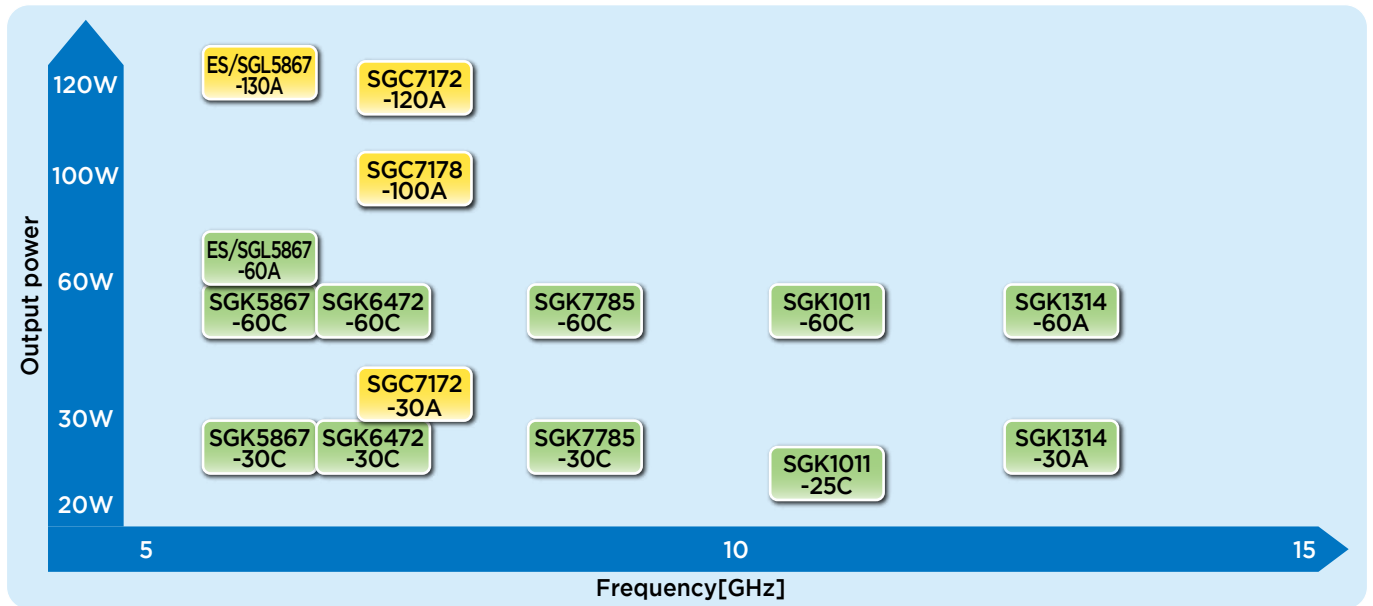
## Features

- High Output Power
- High Gain
- High Efficiency
- Internally Matched



## GaN HEMTs for Satcom Lineup

IBK Package    IK Package



Part Number	Freq. (GHz)	IM3 (dBc)	SCL Pout (dBm)	Pout (dBm)	GL (dB)	$\eta_{add}$ (%)	VDS (V)	IDS(DC) (A)	IDS(RF) (A)	Rth (°C/W)	Pkg
SGK5867-30C	5.85-6.75	-42	29.5	45	15	41	24	1.75	3.2	2.2	IBK
SGK5867-60C	5.85-6.75	-42	32	48	14	39	24	2.6	6.4	1.3	
SGK6472-30C	6.4-7.2	-42	29.5	45	14.5	40	24	1.75	3.2	2.2	
SGK6472-60C	6.4-7.2	-42	32	48	13.5	41	24	2.6	6.4	1.3	
SGK7785-30C	7.7-8.5	-42	29.5	45	14	44	24	1.75	3.2	2.2	
SGK7785-60C	7.7-8.5	-42	32	48	13	40	24	2.6	6.4	1.3	
SGK1011-25C	10.7-11.7	-42	29	45.5	11	40	24	1.2	3	1.9	
SGK1011-60C	10.7-11.7	-40	32	48.5	10	35	24	2.6	7.1	1.1	
SGK1314-30A	13.75-14.5	-30	38.5	45	8.5	32	24	0.9	3.3	1.5	
SGK1314-60A	13.75-14.5	-30	41.5	48	8.5	32	24	1.8	6.6	0.8	
SGC7178-100A	7.1-7.8	-27	44	50	12	36	35	0.8	6	0.65	IK
SGC7172-30A	7.14-7.24	-30	38	45.15	12.15	45	50	0.2	1.4	2.3	
SGC7172-120A	7.14-7.24	-33	44	51.3	12.3	43	50	1.3	5.9	0.65	
* ES/SGL5867-60A	5.85-6.75	-30	41	48	14	40	40	0.4	5.0	1.2	IBK
* ES/SGL5867-130A	5.85-6.75	-30	44	51	13.5	40	40	0.8	8.0	0.7	IK

\* Under Development

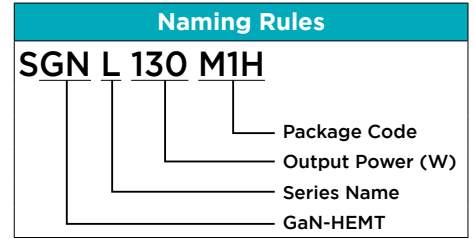
## Product Photo



# GaN HEMTs for General Purpose

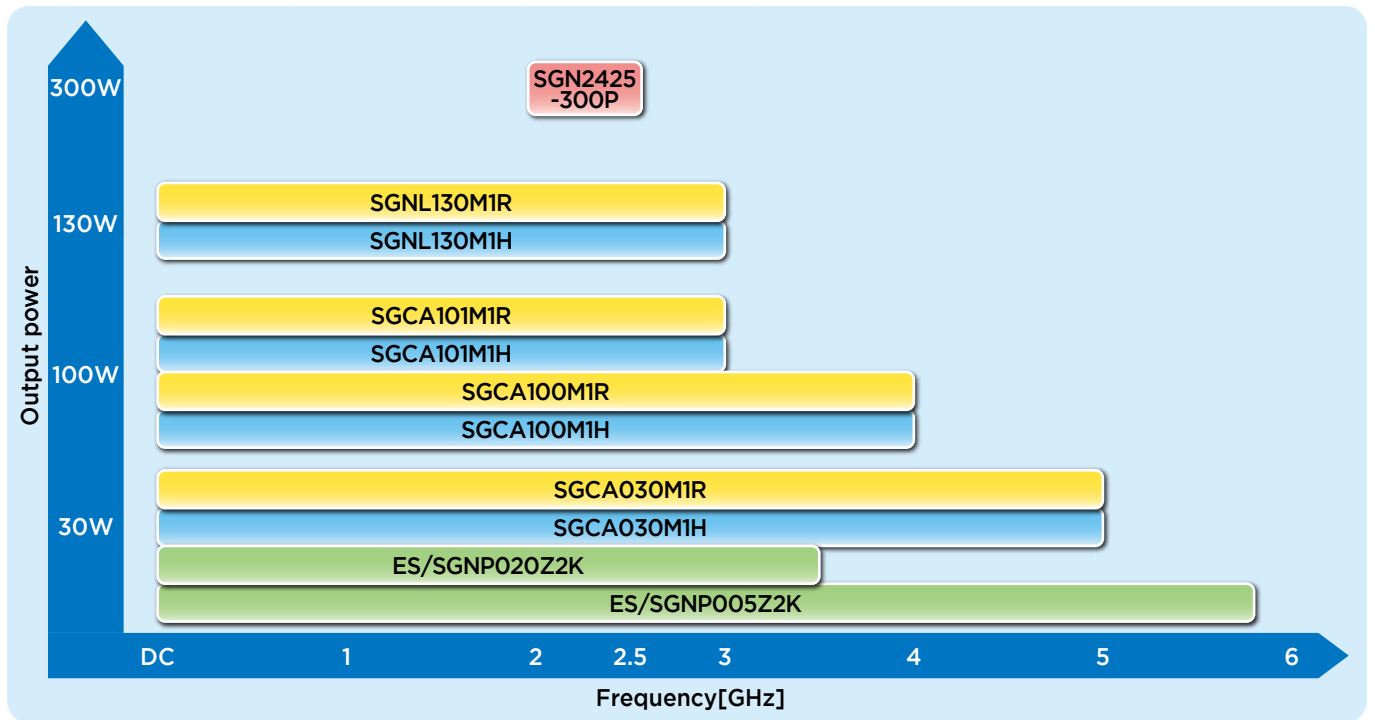
## Features

- High Power up to 315W(typ)
- High Efficiency
- CW Operable
- Concurrent Broadband Operation
- Small Flangeless Package



## GaN HEMTs for General Purpose Lineup

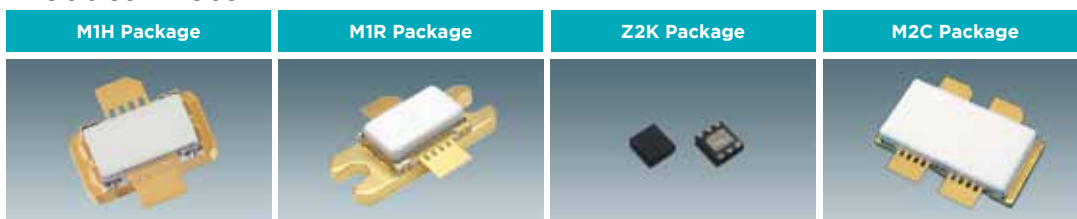
- M2C Package
- Z2K Package
- M1R Package
- M1H Package



Part Number	Freq. (GHz)	Operation	VDS (V)	Spec. frequency	Pout Typ. (dBm)	Gp Typ. (dB)	$\eta_D$ Typ. (%)	Pkg
ES/SGNP005Z2K	DC-5.8	CW	50	2.45	37.2	21.0 <sup>*1</sup>	70	Z2K
ES/SGNP020Z2K	DC-3.5	CW	50	2.45	43.2	21.0 <sup>*1</sup>	70	
SGCA030M1H	DC-5	CW	50	5	45.5	9.5	53	M1H
SGCA030M1R	DC-5	CW	50	5	45.5	9.5	53	M1R
SGCA100M1H	DC-4	CW	50	3.9	50.5	14.5	48	M1H
SGCA100M1R	DC-4	CW	50	3.9	50.5	14.5	48	M1R
SGCA101M1H	DC-3	CW	50	3	50.1	12.1	56	M1H
SGCA101M1R	DC-3	CW	50	3	50.1	12.1	56	M1R
SGNL130M1H	DC-3.0	CW	50	3	51.9	15.9	56.5	M1H
SGNL130M1R	DC-3.0	CW	50	3	51.9	15.9	56.5	M1R
SGN2425-300P	2.4-2.5	CW	50	2.45	55 <sup>*2</sup>	22.0 <sup>*1</sup>	77	M2C

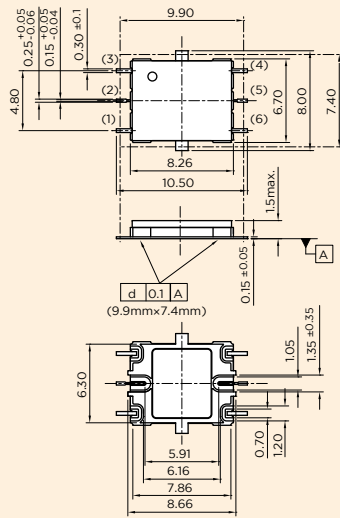
\* 1 : Linear Gain  
\* 2 : P4dB

## Product Photo



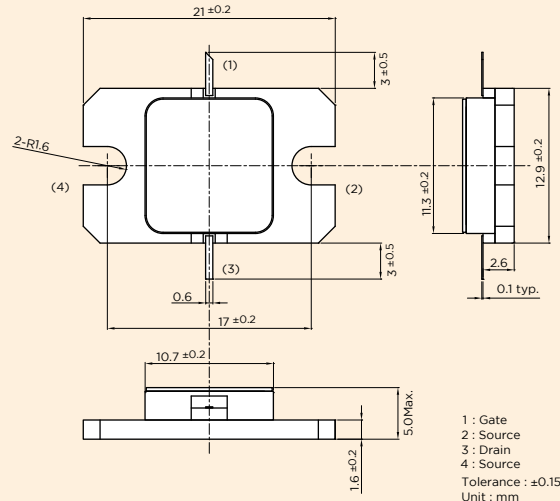
# Packages

## VU



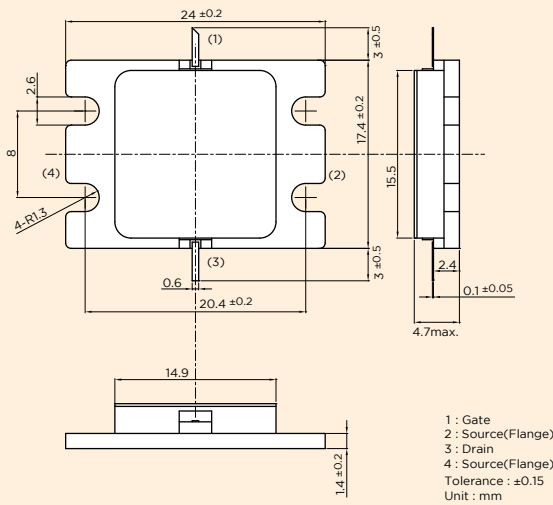
Tolerance :  $\pm 0.15$   
Unit : mm

## IBK



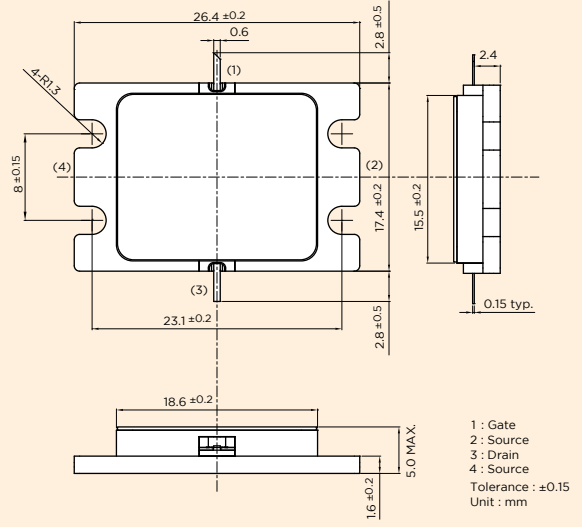
1 : Gate  
2 : Source  
3 : Drain  
4 : Source  
Tolerance :  $\pm 0.15$   
Unit : mm

## IK



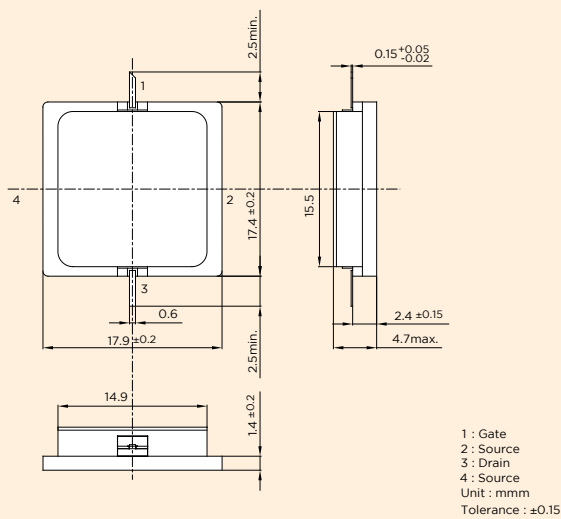
1 : Gate  
2 : Source(Flange)  
3 : Drain  
4 : Source(Flange)  
Tolerance :  $\pm 0.15$   
Unit : mm

## I2F



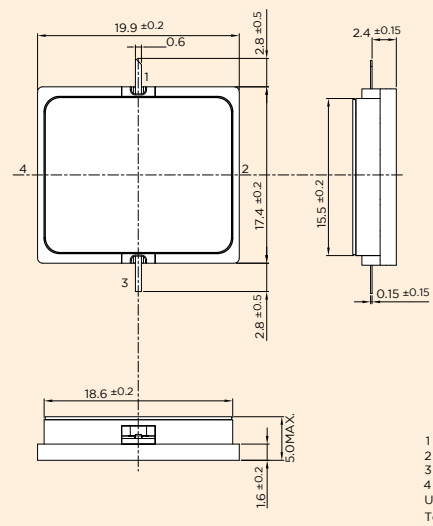
1 : Gate  
2 : Source  
3 : Drain  
4 : Source  
Tolerance :  $\pm 0.15$   
Unit : mm

## I2K



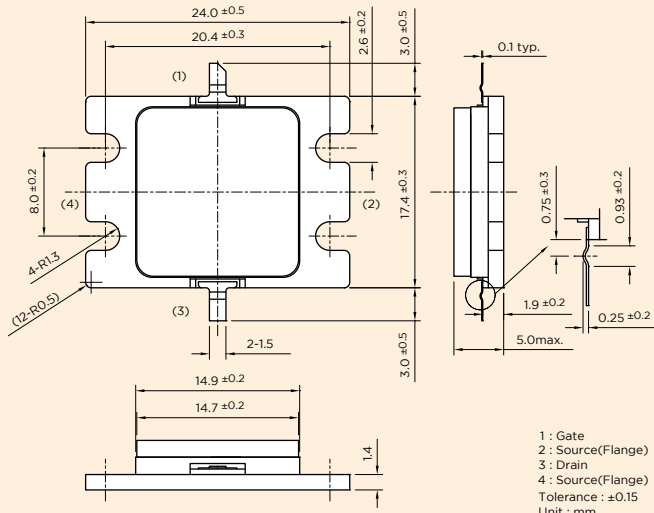
1 : Gate  
2 : Source  
3 : Drain  
4 : Source  
Unit : mmm  
Tolerance :  $\pm 0.15$

## I2G



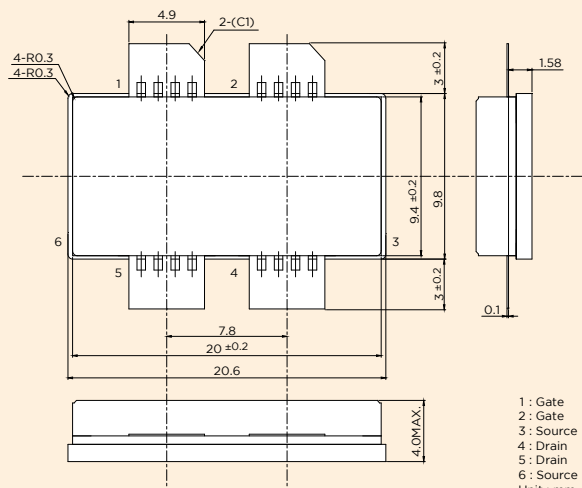
1 : Gate  
2 : Source  
3 : Drain  
4 : Source  
Unit : mm  
Tolerance :  $\pm 0.15$

### IV



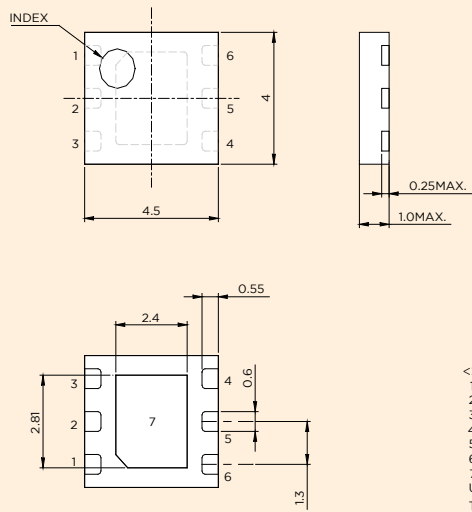
- 1 : Gate
  - 2 : Source(Flange)
  - 3 : Drain
  - 4 : Source(Flange)
- Tolerance : ±0.15  
Unit : mm

### M2C



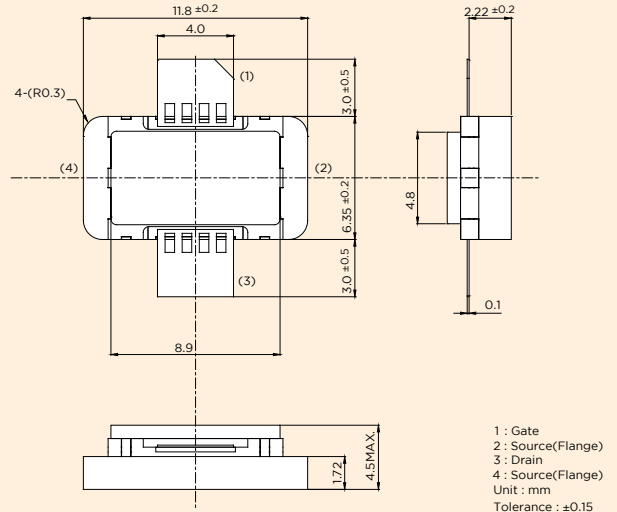
- 1 : Gate
  - 2 : Gate
  - 3 : Source
  - 4 : Drain
  - 5 : Drain
  - 6 : Source
- Unit : mm  
Tolerance : ±0.15

### Z2K



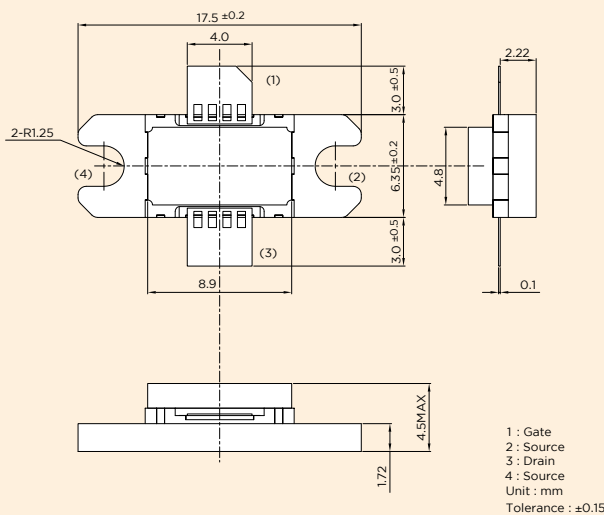
- <Single Type>
- 1 : NC
  - 2 : Gate
  - 3 : NC
  - 4 : NC
  - 5 : Drain
  - 6 : NC
  - 7 : Source
- Unit : mm  
Tolerance : ±0.15

### M1H



- 1 : Gate
  - 2 : Source(Flange)
  - 3 : Drain
  - 4 : Source(Flange)
- Unit : mm  
Tolerance : ±0.15

### M1R



- 1 : Gate
  - 2 : Source
  - 3 : Drain
  - 4 : Source
- Unit : mm  
Tolerance : ±0.15

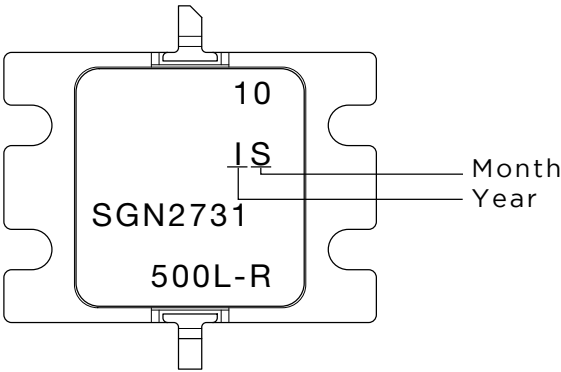
# Sealing Rules

■ Year/Month code

Year	2017	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028
Code	Z	A	B	C	D	E	F	G	H	I	J	K

Note: Code letter is cycling 25 alphabet without Q.

Month	1	2	3	4	5	6	7	8	9	10	11	12
Code	H	M	N	P	R	S	T	U	W	X	Y	Z



Note:  
 Year/Month code consist of two digit alphabet shown at the above table.  
 (e.g. "HS" stands for the device is manufactured in year 2026 (Year code "I") and June (Month code "S"). See the above table.)

# Creating Value for Customers

## Corporate Quality Assurance

Sumitomo Electric strives to achieve the highest quality and reliability performance on all the products it supplies. This is accomplished through a systemic approach that emphasizes quality at every stage of product development through the manufacturing process. Quality is built into the product from design to wafer fabrication, test, and assembly. Sumitomo Electric has a Quality Management System that is certified to ISO9000 (ISO9001: 2015) and Aerospace Quality Management System JIS Q 9100 : 2016. This system assures customers the highest quality product with long term reliability required for their applications.

## Quality Management

### ISO9001 : 2015/JIS Q 9001 : 2015 (Certificate Number : JMI-0278)

Registration Date : September 17, 1993  
Last Renewal Date : September 15, 2024  
Expiry Date : September 14, 2027



### JIS Q 9100:2016(AS9100D, prEN9100:2018) (Certificate Number : JQA-AS0068)

Registration Date : August 20, 2010  
Last Renewal Date : September 15, 2024  
Expiry Date : September 14, 2027  
OASIS Identification Number : 6131093485



## Environmental Management

### ISO14001:2015 / JIS Q 14001:2025 Yamanashi Plant (Certificate Number : EC98J1050)

Registration Date : August 25, 1998  
Last Renewal Date : August 25, 2025  
Expiry Date : August 24, 2028



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 **ATTENTION**

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Information in this document is subject to change without notice.

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